


## DESCRIPTION

The RH1013M is the first precision dual operational amplifier which directly upgrades designs in the industry standard 8-pin DIP LM158/MC1558/OP-221 pin configuration. Low offset voltage (300 $\mu$ V max), low drift ( $\leq 2.5\mu$ V/ $^{\circ}$ C), low offset current ( $\leq 1.5$ nA), and high gain (1.2 million min) combine to make the RH1013M two truly precision amplifiers in one package.

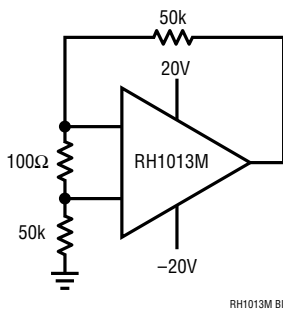
The wafer lots are processed to Linear Technology's in-house Class S flow to yield circuits usable in stringent military applications.

## ABSOLUTE MAXIMUM RATINGS

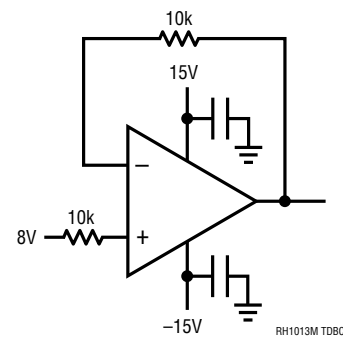
Supply Voltage .....	$\pm 22$ V
Differential Input Voltage .....	$\pm 30$ V
Input Voltage .....	Equal to Positive Supply Voltage
.....	5V Below Negative Supply Voltage
Output Short-Circuit Duration .....	Indefinite
Operating Temperature Range .....	$-55^{\circ}$ C to $125^{\circ}$ C
Storage Temperature Range .....	$-65^{\circ}$ C to $150^{\circ}$ C
Lead Temperature (Soldering, 10 sec) .....	$300^{\circ}$ C

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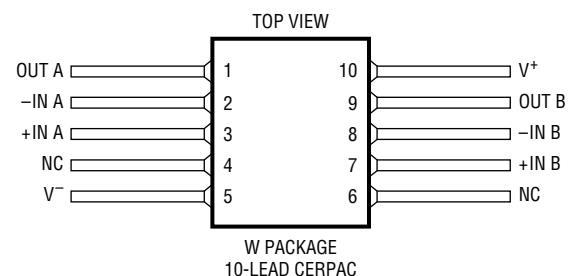
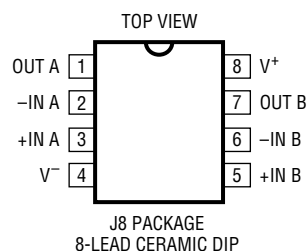
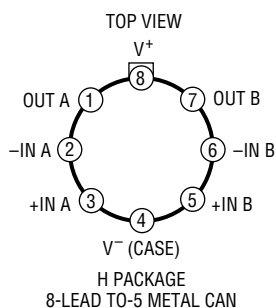
## BURN-IN CIRCUIT



## TOTAL DOSE BIAS CIRCUIT



## PACKAGE/ORDER INFORMATION



**TABLE 1: ELECTRICAL CHARACTERISTICS** (Pre-Irradiation) $V_S = \pm 15V$ ,  $V_{CM} = 0V$ , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	NOTES	$T_A = 25^\circ C$			SUB-GROUP	$-55^\circ C \leq T_A \leq 125^\circ C$			SUB-GROUP	UNITS
				MIN	TYP	MAX		MIN	TYP	MAX		
$V_{OS}$	Input Offset Voltage					300	1		550	2,3	$\mu V$	
				2		450	1		750	3	$\mu V$	
		$V_{CM} = 0.1V$							750	2	$\mu V$	
$\frac{\Delta V_{OS}}{\Delta Temp}$	Average Tempco of Offset Voltage		1						2.5		$\mu V/^\circ C$	
$\frac{\Delta V_{OS}}{\Delta Time}$	Long Term $V_{OS}$ Stability				0.5						$\mu V/Mo$	
$I_{OS}$	Input Offset Current					10	1		20	2,3	nA	
				2		10	1		20	2,3	nA	
$I_B$	Input Bias Current					30	1		45	2,3	nA	
				2		50	1		120	2,3	nA	
$e_n$	Input Noise Voltage	0.1Hz to 10Hz				0.55					$\mu V_{P-P}$	
	Input Noise Voltage	$f_0 = 10Hz$				24					$nV/\sqrt{Hz}$	
	Density	$f_0 = 1000Hz$				22					$nV/\sqrt{Hz}$	
$i_n$	Input Noise Current Density	$f_0 = 10Hz$				0.07					$pA/\sqrt{Hz}$	
$R_{IN}$	Input Resistance	Differential	1	70							$M\Omega$	
		Common Mode			4						$G\Omega$	
$A_{VOL}$	Large-Signal Voltage Gain	$V_0 = \pm 10V$ , $R_L \geq 2k$		1.2			4	0.25		5,6	$V/\mu V$	
		$V_0 = \pm 10V$ , $R_L \geq 600\Omega$		0.5			4				$V/\mu V$	
		$V_0 = 5mV$ to $4V$ , $R_L = 500\Omega$	2	1							$V/\mu V$	
	Input Voltage Range		1	13.5							V	
			1	-15.0							V	
			1,2	3.5							V	
			1,2	0							V	
CMRR	Common-Mode Rejection Ratio	$V_{CM} = 13.5V$ , $-15V$		97			1				dB	
		$V_{CM} = 13V$ , $-14.9V$						94		2,3	dB	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 2V$ to $\pm 18V$		100			1	97		2,3	dB	
	Channel Separation	$V_0 = \pm 10V$ , $R_L = 2k$		120			1				dB	
$V_{OUT}$	Output Voltage Swing	$R_L \geq 2k$		$\pm 12.5$			4	$\pm 11.5$		5,6	V	
		Output Low, No Load	2		25	4					mV	
		Output Low, $600\Omega$ to GND	2		10	4		18	5,6		mV	
		Output Low, $I_{SINK} = 1mA$	2		350	4					mV	
		Output High, No Load	2	4.0		4					V	
		Output High, $600\Omega$ to GND	2	3.4		4	3.1		5,6		V	
SR	Slew Rate			0.2			4				$V/\mu s$	
$I_S$	Supply Current	Per Amplifier			0.55		1	0.70		2,3	mA	
			2		0.50		1	0.65		2,3	mA	

**TABLE 1A: ELECTRICAL CHARACTERISTICS (Post-Irradiation)** $V_S = \pm 15V$ ,  $V_{CM} = 0V$ ,  $T_A = 25^\circ C$ , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	NOTES	10KRAD(Si)		20KRAD(Si)		50KRAD(Si)		100KRAD(Si)		200KRAD(Si)		UNITS
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
$V_{OS}$	Input Offset Voltage			450		450		600		750		900		$\mu V$
			2	600		600		750		900				$\mu V$
$I_{OS}$	Input Offset Current			10		10		15		20		25		nA
			2	10		10		15		20				nA
$I_B$	Input Bias Current			60		75		100		175		250		nA
			2	80		100		125		200				nA
	Input Voltage Range		1	13.5		13.5		13.5		13.5		13.5		V
			1	-15.0		-15.0		-15.0		-15.0		-15.0		V
			2	3.5		3.5		3.5		3.5				V
			2	0		0		0		0				V
CMRR	Common-Mode Rejection Ratio	$V_{CM} = 13V, -15V$		97		97		94		90		86		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 10V$ to $\pm 18V$		100		98		94		86		80		dB
$A_{VOL}$	Large-Signal Voltage Gain	$R_L \geq 10k, V_O = \pm 10V$		500		200		100		50		25		V/mV
$V_{OUT}$	Maximum Output Voltage Swing	$R_L \geq 10k$		$\pm 12.5$		$\pm 12.5$		$\pm 12.5$		$\pm 12.5$		$\pm 12.5$		V
			2	25		30		40		50				mV
			2	10		10		10		10				mV
			2	0.6		0.8		1.0		1.6				V
			2	4.0		4.0		4.0		4.0				V
			2	3.4		3.2		3.0		2.8				V
SR	Slew Rate	$R_L \geq 10k$		0.13		0.12		0.11		0.07		0.01		V/ $\mu s$
$I_S$	Supply Current	Per Amplifier		0.55		0.55		0.55		0.55		0.55		mA
			2	0.50		0.50		0.50		0.50				mA

**Note 1:** Guaranteed by design, characterization, or correlation to other tested parameters..

**Note 2:** Specification applies for  $V_S^+ = 5V$ ,  $V_S^- = 0V$ ,  $V_{CM} = 0V$ ,  $V_{OUT} = 1.4V$ .

**TABLE 2: ELECTRICAL TEST REQUIREMENTS**

MIL-STD-883 TEST REQUIREMENTS	SUBGROUP
Final Electrical Test Requirements (Method 5004)	1*,2,3,4,5,6
Group A Test Requirements (Method 5005)	1,2,3,4,5,6
Group B and D for Class S, and Group C and D for Class B End Point Electrical Parameters (Method 5005)	1,2,3

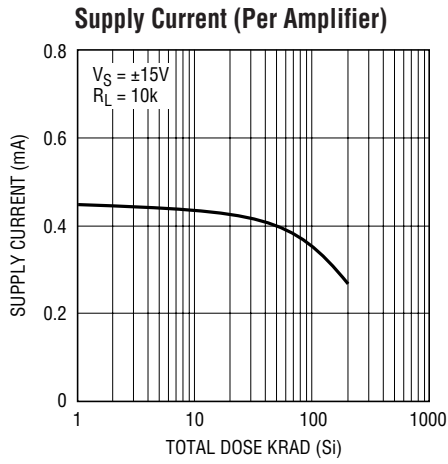
\* PDA applies to subgroup 1. See PDA Test Notes.

**PDA Test Notes**

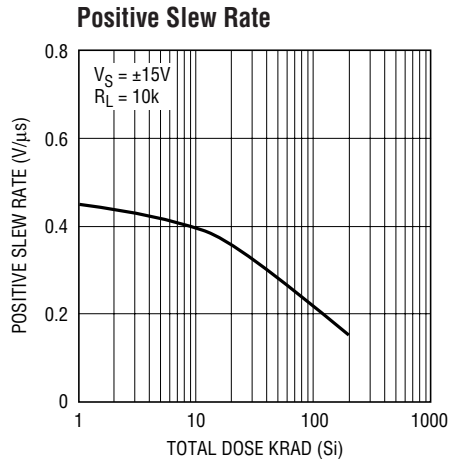
The PDA is specified as 5% based on failures from group A, subgroup 1, tests after cooldown as the final electrical test in accordance with method 5004 of MIL-STD-883. The verified failures of group A, subgroup 1, after burn-in divided by the total number of devices submitted for burn-in in that lot shall be used to determine the percent for the lot.

Linear Technology Corporation reserves the right to test to tighter limits than those given.

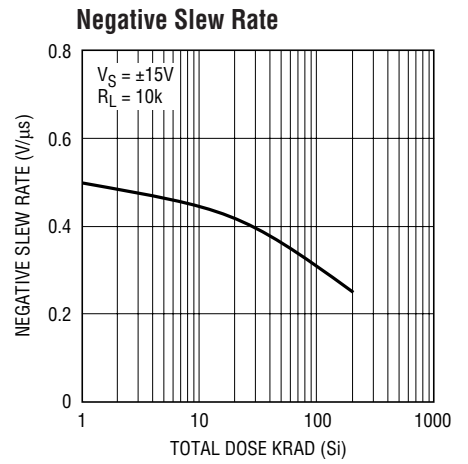
**TYPICAL PERFORMANCE CHARACTERISTICS**



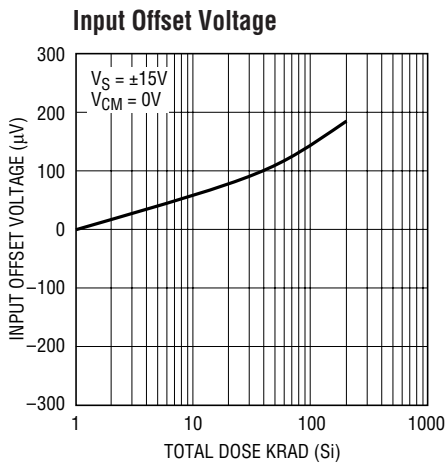
RH1013M G01



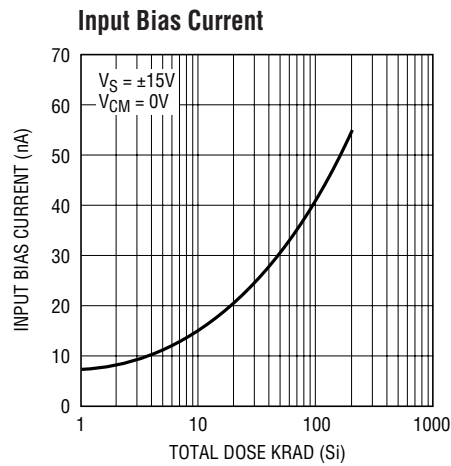
RH1013M G02



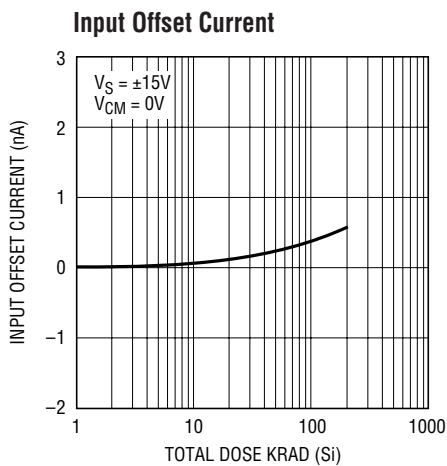
RH1013M G03



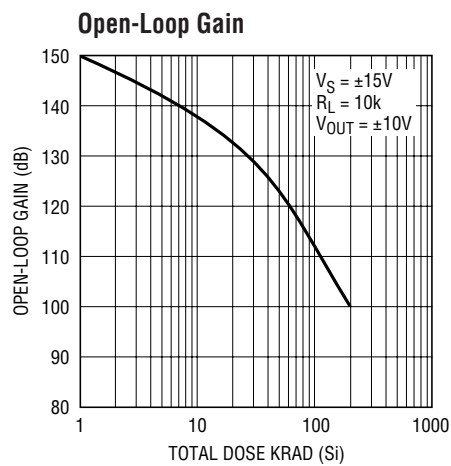
RH1013M G04



RH1013M G05



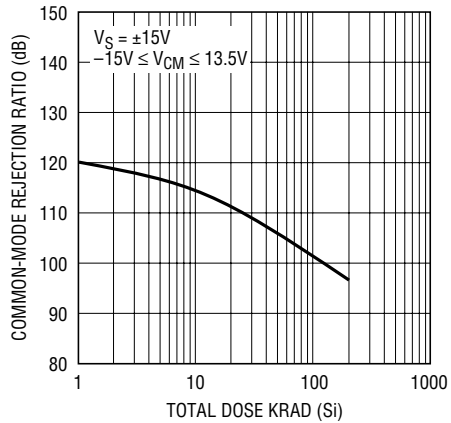
RH1013M G06



RH1013M G07

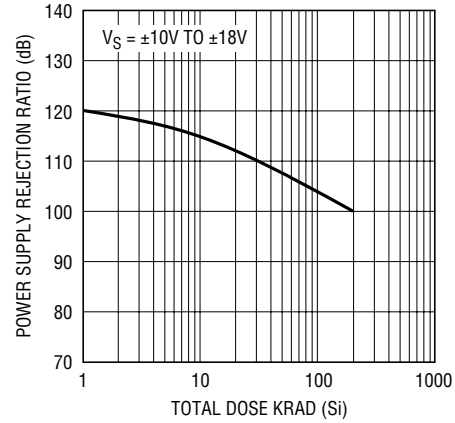
## TYPICAL PERFORMANCE CHARACTERISTICS

### Common-Mode Rejection Ratio



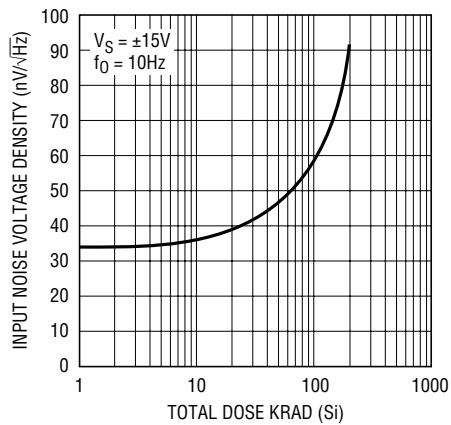
RH1013M G08

### Power Supply Rejection Ratio



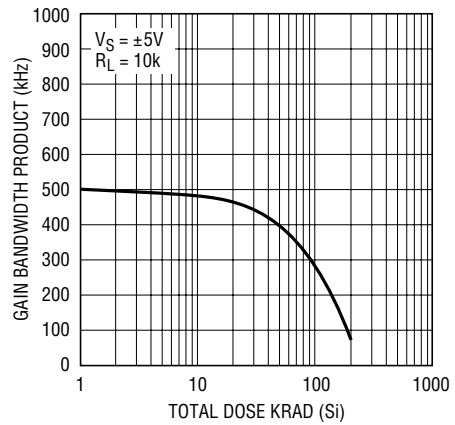
RH1013M G09

### Input Noise Voltage Density



RH1013M G10

### Gain Bandwidth Product



RH1013M G11

# RH1013M

## Rad Hard

This table provides example specifications for our Rad Hard products. For complete Rad Hard data sheets, contact 1-800-4-LINEAR.

DEVICE	SYMBOL	CONDITIONS	10Krad (Si)		20Krad (Si)		50Krad (Si)		80Krad (Si)		100Krad (Si)		200Krad (Si)		UNITS	PACKAGE OPTIONS
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
RH07	$V_{OS}$ $I_{OS}$		90 2.8		150 4		200 8			250 12		300 20		$\mu V$ nA	J8, H	
RH27C	$V_{OS}$ $I_{OS}$		100 75		130 75		180 90			280 120		400 180		$\mu V$ nA	H, W	
RH37C	$V_{OS}$ $I_{OS}$		100 75		130 75		180 90			280 120		400 180		$\mu V$ nA	H, W	
RH101A	$V_{OS}$ $I_{OS}$		2 10		2 10		2 10			2 10		3 20		mV nA	H, W	
RH108A	$V_{OS}$ $I_{OS}$		0.5 0.2		0.5 0.2		0.5 0.2		1.0 0.2					mV nA	H, W	
RH117	$V_{REF}$	$3V \leq (V_{IN} - V_{OUT}) \leq 40V$ $10mA \leq I_{OUT} \leq I_{MAX}, P \leq P_{MAX}$	1.20	1.30	1.20	1.30	1.20	1.30			1.20	1.30			V	H, K
RH118	$V_{OS}$ SR	$V_S = \pm 15V, A_V = 1$	50	4	50	4	50	4		50	4	50	10	mV V/ $\mu s$	H, W	
RH119	$V_{OS}$ $I_{OS}$		4 75		4 100		4 150			4 300		8 500		mV nA	H, J, W	
RH129	$V_Z$ $\Delta V_Z / \Delta TEMP$	RH129A RH129B RH129C	6.7 7.2 10 20 50	7.2 10 20 50	6.7 7.2 10 20 50	7.2 10 20 50	6.7 7.2 10 20 50	7.2 10 20 50		6.7 7.2 15 25 55	7.2 10 20 30 60	6.7 7.2 15 25 60	7.2 10 20 30 60	V ppm/ $^{\circ}C$ ppm/ $^{\circ}C$ ppm/ $^{\circ}C$	H	
RH137	$V_{REF}$	$ V_{IN} - V_{OUT}  \leq 5V, I_{OUT} = 10mA$ $3V \leq  V_{IN} - V_{OUT}  \leq 40V$ $10mA \leq I_{OUT} \leq I_{MAX}, P \leq P_{MAX}$	-1.225 -1.275 -1.2 -1.3	-1.225 -1.275 -1.2 -1.3	-1.225 -1.275 -1.2 -1.3	-1.225 -1.275 -1.2 -1.3	-1.225 -1.275 -1.2 -1.3	-1.225 -1.275 -1.2 -1.3		-1.225 -1.275 -1.2 -1.3	-1.225 -1.275 -1.2 -1.3	-1.225 -1.275 -1.2 -1.3	-1.225 -1.275 -1.2 -1.3	V V	K, H	
RH1009	$V_Z$ $\Delta V_Z / \Delta I_Z$		2.495 2.505 6	2.495 2.505 6	2.495 2.505 6	2.495 2.505 6	2.495 2.505 8			2.495 2.505 10	2.495 2.505 12	2.495 2.505 12	2.495 2.505 12	V mV	H	
RH1011	$V_{OS}$ $I_{OS}$		1.5 4		1.5 4		1.5 4			1.5 20		2 50		mV nA	H, J8, W	
RH1013	$V_{OS}$ $I_{OS}$		450 10		450 10		600 15			750 20		900 25		$\mu V$ nA	H, J8, W	
RH1014	$V_{OS}$ $I_{OS}$		450 10		450 10		600 15			750 20		900 25		$\mu V$ nA	J, W	
RH1021-5	$V_{OUT}$ TCV <sub>OUT</sub>	RH1021CM-5 RH1021BM-5, DM-5 RH1021BM-5 RH1021CM-5, DM-5	4.9975 5.0025 4.95 5.05 5 20	4.995 5.005 4.945 5.055 5 20	4.993 5.007 4.942 5.058 5 20	4.993 5.007 4.942 5.058 5 20	4.993 5.007 4.942 5.058 5 20	4.993 5.007 4.942 5.058 5 20		4.9925 5.008 4.94 5.06 4.935 5.065	4.99 5.01 7 10 25	4.99 5.01 7 10 25	4.99 5.01 7 10 25	V V ppm/ $^{\circ}C$ ppm/ $^{\circ}C$	H	
RH1021-7	$V_{OUT}$ TCV <sub>OUT</sub>	RH1021BM-7 RH1021DM-7	6.95 7.05 5 20	6.95 7.05 5 20	6.95 7.05 5 20	6.95 7.05 5 20	6.95 7.05 5 20	6.95 7.05 5 20		6.94 7.06 7 22	6.93 7.07 10 25	6.93 7.07 10 25	6.93 7.07 10 25	V ppm/ $^{\circ}C$ ppm/ $^{\circ}C$	H	
RH1021-10	$V_{OUT}$ TCV <sub>OUT</sub>	RH1021CM-10 RH1021BM-10, DM-10 RH1021BM-10 RH1021CM-10, DM-10	9.995 10.005 9.95 10.05 5 20	9.99 10.01 9.945 10.055 5 20	9.987 10.013 9.942 10.06 5 20	9.987 10.013 9.942 10.06 5 20	9.987 10.013 9.942 10.06 5 20	9.987 10.013 9.942 10.06 5 20		9.985 10.015 9.98 10.06 9.935 10.065	9.98 10.02 9.935 10.065	9.98 10.02 9.935 10.065	9.98 10.02 9.935 10.065	V V ppm/ $^{\circ}C$ ppm/ $^{\circ}C$	H	
RH1056A	$V_{OS}$ $I_{OS}$		180 $\pm 10$		180 $\pm 50$		250 $\pm 150$			450 $\pm 250$		450 $\pm 350$		$\mu V$ pA	H, W	
RH1078	$V_{OS}$ $I_{OS}$		350 2		500 18		650 13	75k 18	800	1000				$\mu V$ nA	H, J8, W J, W	
RH1086	$V_{REF}$ Dropout V	$I_{OUT} = 10mA$ $10mA \leq I_{OUT} \leq I_{FULL LOAD}$ $1.5V \leq (V_{IN} - V_{OUT}) \leq 15V$ $\Delta V_{REF} = 1\%, I_{OUT} = 1.5A (K)$ $\Delta V_{REF} = 1\%, I_{OUT} = 0.5A (H)$	1.258 1.271 1.5		1.257 1.269 1.51		1.253 1.265 1.52			1.247 1.260 1.55		1.241 1.253 1.575		V V V	H, K	

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